SWITCHMODE[™] Power Rectifier

This state-of-the-art device is designed for use in switching power supplies.

Features

- Ultrafast 35 Nanosecond Recovery Time
- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- High Temperature Glass Passivated Junction
- Current Derating @ Both Case and Ambient Temperatures
- Pb–Free Package is Available*

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
Average Rectified Forward Current Total Device, (Rated V_R), $T_C = 150^{\circ}C$ Per Leg Total Device	I _{F(AV)}	8.0 16	A
Peak Rectified Forward Current (Rated V_R , Square Wave, 20 kHz), $T_C = 150^{\circ}C$ – Per Diode Leg	I _{FM}	16	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100	A
Operating Junction Temperature and Storage Temperature	T _J , T _{stg}	–65 to +175	°C

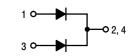
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



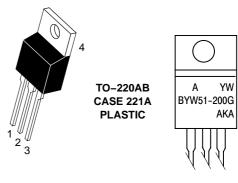
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



А	= Assembly Location
Υ	= Year
W	= Work Week
BYW51-200	= Device Code
G	= Pb–Free Package
AKA	= Diode Polarity

ORDERING INFORMATION

Device	Package	Shipping
BYW51-200	TO-220	50 Units/Rail
BYW51-200G	TO–220 (Pb–Free)	50 Units/Rail

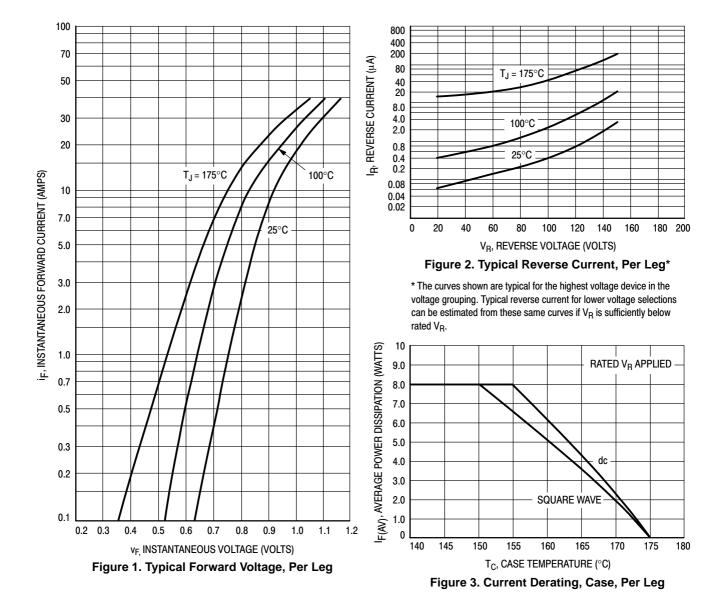
*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

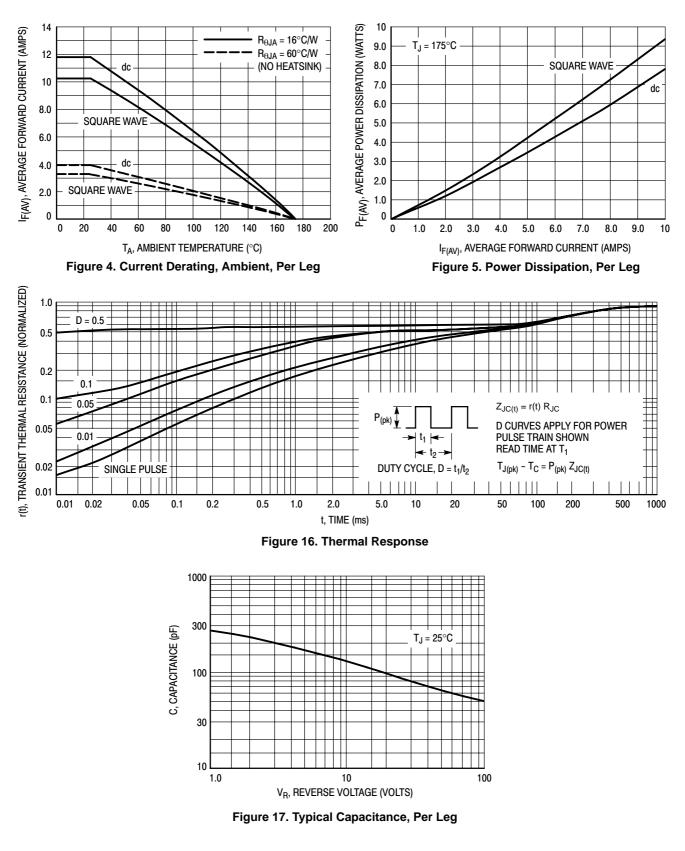
THERMAL CHARACTERISTICS (Per Diode Leg)

Characteristic	Symbol	Value	Unit
Maximum Thermal Resistance, Junction to Case	R _{JC}	3.0	°C/W

Maximum Instantaneous Forward Voltage (Note 1) ($i_F = 8.0 \text{ Amps}, T_C = 100^{\circ}\text{C}$) ($i_F = 8.0 \text{ Amps}, T_C = 25^{\circ}\text{C}$)	۷ _F	0.89 0.97	V
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 100^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$)	i _R	1.0 10	mA
Maximum Reverse Recovery Time $(I_F = 1.0 \text{ Amp, di/dt} = 50 \text{ Amps/s})$ $(I_F = 0.5 \text{ Amp, } I_R = 1.0 \text{ Amp, } I_{REC} = 0.25 \text{ Amp})$	t _{rr}	35 25	ns

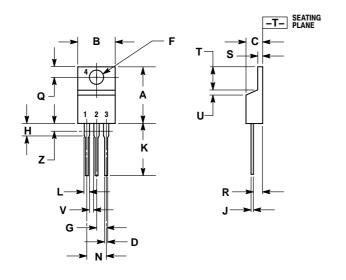
1. Pulse Test: Pulse Width = 300 s, Duty Cycle $\leq 2.0\%$





PACKAGE DIMENSIONS

TO-220AB CASE 221A-09 **ISSUE AA**



NOTES

DIMENSIONING AND TOLERANCING PER ANSI 1. Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

2

DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE 3 ALLOWED.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
-	0.018	0.025	0.46	0.64
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Ø	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

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